

Surface Mount RF PIN Switch and Limiter Diodes

Technical Data

HSMP-382x Series and HSMP-482x Series

Features

- **Diodes Optimized for:** Low Current Switching Low Distortion Attenuating
- Power Limiting/Circuit
 Protection
- Surface Mount SOT-23 and SOT-323 Packages Single and Dual Versions Tape and Reel Options Available
- Low Failure in Time (FIT) Rate^[1]

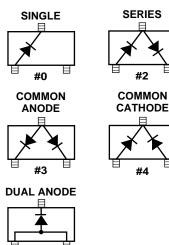
Note:

1. For more information see the Surface Mount PIN Reliability Data Sheet.

Description/Applications

The HSMP-382x series is optimized for switching applications where ultra-low resistance is required. The HSMP-482x diode is ideal for limiting and low inductance switching applications up to 1.5 GHz.

A SPICE model is not available for PIN diodes as SPICE does not provide for a key PIN diode characteristic, carrier lifetime. Package Lead Code Identification, SOT-23 (Top View)



HSMP-4820

Absolute Maximum Ratings^[1] $T_C = +25^{\circ}C$

Symbol	Parameter	Unit	SOT-23	SOT-323
If	Forward Current (1 µs Pulse)	Amp	1	1
P _{IV}	Peak Inverse Voltage	V	50	50
Tj	Junction Temperature	°C	150	150
T _{stg}	Storage Temperature	°C	-65 to 150	-65 to 150
θ_{jc}	Thermal Resistance ^[2]	°C/W	500	150

Notes:

- 1. Operation in excess of any one of these conditions may result in permanent damage to the device.
- 2. T_C = +25°C, where T_C is defined to be the temperature at the package pins where contact is made to the circuit board.

Package Lead Code Identification, SOT-323 (Top View)



Electrical Specifications $T_{\rm C}$ = 25 $^{\circ}{\rm C}$

Part Number HSMP-	Package Marking Code ^[1]	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	Maximum Series Resistance R _S (Ω)	Maximum Total Capacitance C _T (pF)
3820 3822 3823	F0 F2 F3	0 2 3	Single Series Common Anode	50	0.6	0.8
3824 Test Conditions	F4	4	Common Cathode	$V_{\rm R} = V_{\rm BR}$ Measure $I_{\rm R} \le 10 \ \mu {\rm A}$	$\begin{array}{l} f=100 \ \mathrm{MHz} \\ \mathrm{I_{F}}=10 \ \mathrm{mA} \end{array}$	$\begin{array}{l} f=1 \ MHz \\ V_R=20 \ V \end{array}$

High Frequency (Low Inductance, 500 MHz – 3 GHz) PIN Diodes

Part Number HSMP-	Package Marking Code	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	Maximum Series Resistance R _S (Ω)	Typical Total Capacitance C _T (pF)	Maximum Total Capacitance C _T (pF)	Typical Total Inductance L _T (nH)
4820 482B	FA FA	A A	Dual Anode Dual Anode	50	0.6	0.75	1.0	1.0
Test Co	Test Conditions			$\label{eq:VR} \begin{split} V_{\rm R} &= V_{\rm BR} \\ Measure \\ I_{\rm R} &\leq 10 \; \mu {\rm A} \end{split}$	$I_F = 10 \text{ mA}$	$\begin{array}{l} \mathbf{f}=1 \ \mathrm{MHz} \\ \mathbf{V}_{\mathrm{R}}=20 \ \mathrm{V} \end{array}$	$\begin{array}{l} \mathbf{f}=1 \ \mathrm{MHz} \\ \mathbf{V}_{\mathrm{R}}=0 \ \mathrm{V} \end{array}$	f = 500 MHz – 3 GHz

Note:

1. Package marking code is white, except for HSMP-482B, which is laser marked.

Typical Parameters at $T_C = 25^{\circ}C$

Part Number HSMP-			Reverse Recovery Time T _{rr} (ns)	Total Capacitance C _T (pF)
382x	1.5	70	7	0.60 @ 20 V
Test Conditions	$\begin{array}{c} f=100 \ \mathrm{MHz} \\ \mathrm{I_{F}}=10 \ \mathrm{mA} \end{array}$	I _F = 10 mA	$\begin{array}{c} V_{\rm R} = 10 \ {\rm V} \\ I_{\rm F} = 20 \ {\rm mA} \\ 90\% \ {\rm Recovery} \end{array}$	

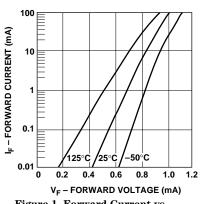
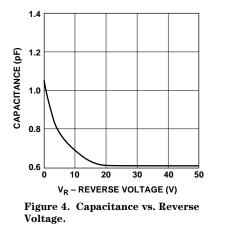


Figure 1. Forward Current vs. Forward Voltage.



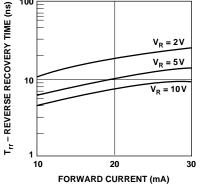
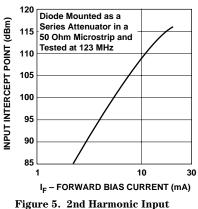
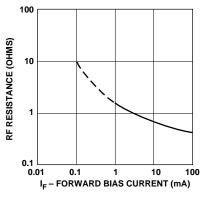
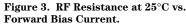


Figure 2. Reverse Recovery Time vs. Forward Current for Various Reverse Voltages.



Intercept Point vs. Forward Bias Current.





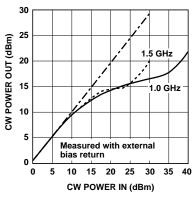


Figure 6. Large Signal Transfer Curve of the HSMP-482x Limiter.



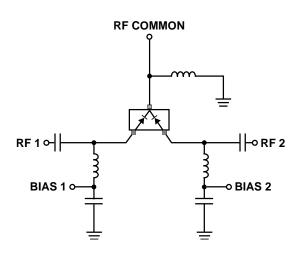


Figure 7. Simple SPDT Switch, Using Only Positive Current.

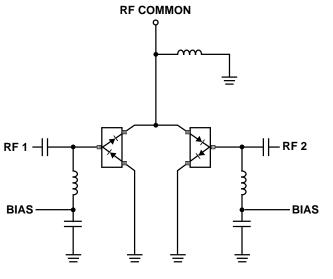
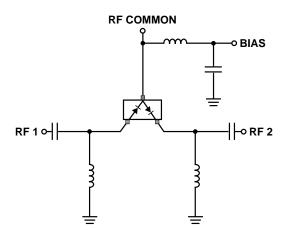


Figure 8. High Isolation SPDT Switch, Dual Bias.



Typical Applications for Multiple Diode Products, continued

Figure 9. Switch Using Both Positive and Negative Bias Current.

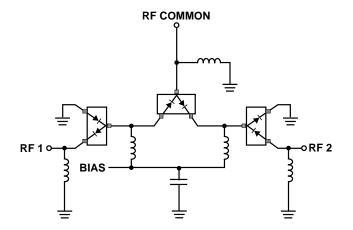


Figure 10. Very High Isolation SPDT Switch, Dual Bias.

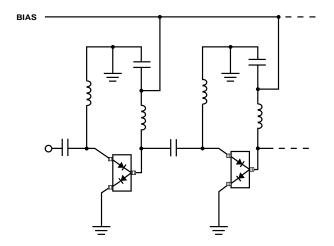


Figure 11. High Isolation SPST Switch (Repeat Cells as Required.

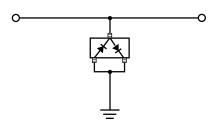


Figure 12. Power Limiter Using HSMP-3822 Diode Pair. See Application Note 1050 for details.

Typical Applications for HSMP-482x Low Inductance Series

Microstrip Series Connection for HSMP-482x Series

In order to take full advantage of the low inductance of the HSMP-482x series when using them in series applications, both lead 1 and lead 2 should be connected together, as shown in Figure 14.

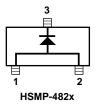


Figure 13. Internal Connections.

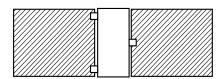


Figure 14. Circuit Layout.

Microstrip Shunt Connections for HSMP-482x Series

In Figure 15, the center conductor of the microstrip line is interrupted and leads 1 and 2 of the HSMP-482x diode are placed across the resulting gap. This forces the 0.5 nH lead inductance of leads 1 and 2 to appear as part of a low pass filter, reducing the shunt parasitic inductance and increasing the maximum available attenuation. The 0.3 nH of shunt inductance external to the diode is created by the via holes, and is a good estimate for 0.032" thick material.

Co-Planar Waveguide Shunt Connection for HSMP-482x Series

Co-Planar waveguide, with ground on the top side of the printed circuit board, is shown in Figure 17. Since it eliminates the need for via holes to ground, it offers lower shunt parasitic inductance and higher maximum attenuation when compared to a microstrip circuit. See AN1050 for details.



0.8 pF

0.3 nH

0.3 nH

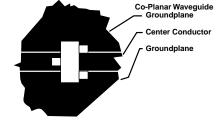


Figure 17. Circuit Layout.

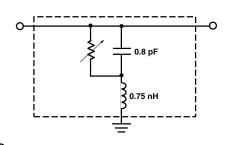


Figure 18. Equivalent Circuit.

Assembly Information SOT-323 PCB Footprint

A recommended PCB pad layout for the miniature SOT-323 (SC-70) package is shown in Figure 19 (dimensions are in inches). This layout provides ample allowance for package placement by automated assembly equipment without adding parasitics that could impair the performance.

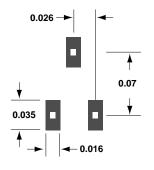


Figure 19. PCB Pad Layout (dimensions in inches).

SOT-23 PCB Footprint

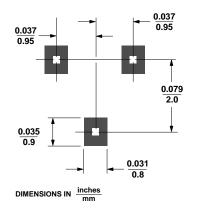


Figure 20. PCB Pad Layout.

SMT Assembly

Reliable assembly of surface mount components is a complex process that involves many material, process, and equipment factors, including: method of heating (e.g., IR or vapor phase reflow, wave soldering, etc.) circuit board material, conductor thickness and pattern, type of solder alloy, and the thermal conductivity and thermal mass of components. Components with a low mass, such as the SOT-323/-23 package, will reach solder reflow temperatures faster than those with a greater mass.

Agilent's diodes have been qualified to the time-temperature profile shown in Figure 21. This profile is representative of an IR reflow type of surface mount assembly process.

After ramping up from room temperature, the circuit board with components attached to it (held in place with solder paste) passes through one or more preheat zones. The preheat zones increase the temperature of the board and components to prevent thermal shock and begin evaporating solvents from the solder paste. The reflow zone briefly elevates the temperature sufficiently to produce a reflow of the solder.

The rates of change of temperature for the ramp-up and cooldown zones are chosen to be low enough to not cause deformation of the board or damage to components due to thermal shock. The maximum temperature in the reflow zone (T_{MAX}) should not exceed 235°C.

These parameters are typical for a surface mount assembly process for Agilent diodes. As a general guideline, the circuit board and components should be exposed only to the minimum temperatures and times necessary to achieve a uniform reflow of solder.

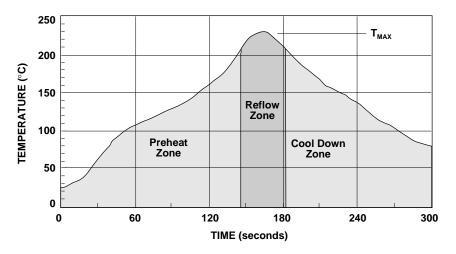
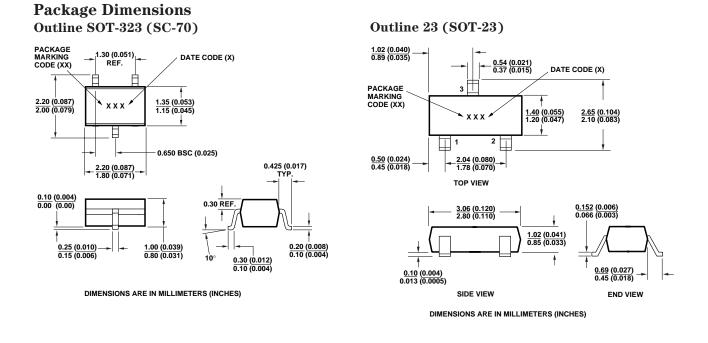


Figure 21. Surface Mount Assembly Profile.

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Package Characteristics

Lead Material	. Copper (SOT-323); Alloy 42 (SOT-23)
Lead Finish	Tin-Lead 85-15%
Maximum Soldering Temperature	
Minimum Lead Strength	
Typical Package Inductance	
Typical Package Capacitance	

Ordering Information

Specify part number followed by option. For example:

H<u>SMP</u> - <u>382x</u> - <u>XXX</u>

Bulk or Tape and Reel Option Part Number; x = Lead Code Surface Mount PIN

Option Descriptions

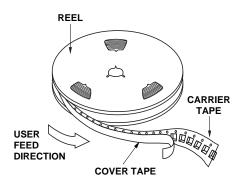
-BLK = Bulk, 100 pcs. per antistatic bag -TR1 = Tape and Reel, 3000 devices per 7" reel -TR2 = Tape and Reel, 10,000 devices per 13" reel

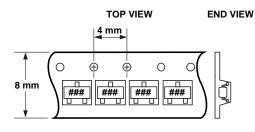
Tape and Reeling conforms to Electronic Industries RS-481, "Taping of Surface Mounted Components for Automated Placement."

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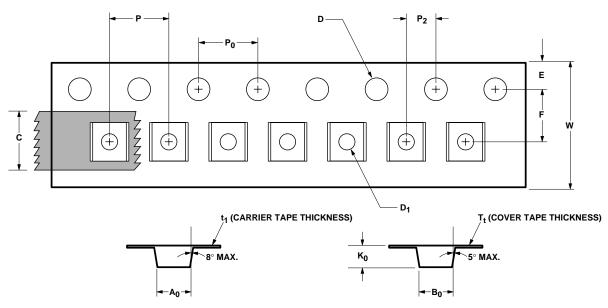
Device Orientation





Note: "###" represents Package Marking Code, Date Code.

Tape Dimensions For Outline SOT-323 (SC-70 3 Lead)



	DESCRIPTION	SYMBOL	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH WIDTH DEPTH PITCH	А ₀ В ₀ К ₀ Р	$\begin{array}{c} \textbf{2.24} \pm \textbf{0.10} \\ \textbf{2.34} \pm \textbf{0.10} \\ \textbf{1.22} \pm \textbf{0.10} \\ \textbf{4.00} \pm \textbf{0.10} \end{array}$	$\begin{array}{c} \textbf{0.088} \pm \textbf{0.004} \\ \textbf{0.092} \pm \textbf{0.004} \\ \textbf{0.048} \pm \textbf{0.004} \\ \textbf{0.157} \pm \textbf{0.004} \end{array}$
	BOTTOM HOLE DIAMETER	D ₁	1.00 + 0.25	0.039 + 0.010
PERFORATION	DIAMETER PITCH POSITION	D P ₀ E	$\begin{array}{c} 1.55 \pm 0.05 \\ 4.00 \pm 0.10 \\ 1.75 \pm 0.10 \end{array}$	$\begin{array}{c} \textbf{0.061} \pm \textbf{0.002} \\ \textbf{0.157} \pm \textbf{0.004} \\ \textbf{0.069} \pm \textbf{0.004} \end{array}$
CARRIER TAPE	WIDTH THICKNESS	w t ₁	$\begin{array}{c} 8.00 \pm 0.30 \\ 0.255 \pm 0.013 \end{array}$	$\begin{array}{c} \textbf{0.315} \pm \textbf{0.012} \\ \textbf{0.010} \pm \textbf{0.0005} \end{array}$
COVER TAPE	WIDTH TAPE THICKNESS	C T _t	$\begin{array}{c} 5.4 \pm 0.10 \\ 0.062 \pm 0.001 \end{array}$	$\begin{array}{c} \textbf{0.205} \pm \textbf{0.004} \\ \textbf{0.0025} \pm \textbf{0.00004} \end{array}$
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	$\textbf{0.138} \pm \textbf{0.002}$
	CAVITY TO PERFORATION (LENGTH DIRECTION)	P ₂	$\textbf{2.00} \pm \textbf{0.05}$	0.079 ± 0.002

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